



FR601S-FR607S

Fast Recovery Rectifiers



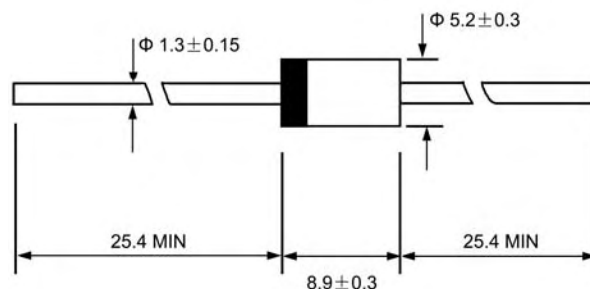
VOLTAGE RANGE: 50 --- 1000 V

CURRENT: 6.0 A

DO - 27

Features

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon, Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0



Mechanical Data

- ◇ Case: JEDEC DO-27, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 unces, 1.15 grams
- ◇ Mounting position: Any

Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		FR 601S	FR 602S	FR 603S	FR 604S	FR 605S	FR 606S	FR 607S	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 9.5mm lead length, @T _A =75°C	I _{F(AV)}	6.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @T _J =125°C	I _{FSM}	300.0							A
Maximum instantaneous forward voltage @ 6.0 A	V _F	1.3							V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =100°C	I _R	10.0 200.0							μ A
Maximum reverse recovery time (Note1)	t _{rr}	150				250	500		ns
Typical junction capacitance (Note2)	C _J	150							pF
Typical thermal resistance (Note3)	R _{θJA}	12							°C/W
Operating junction temperature range	T _J	- 55---- +150							°C
Storage temperature range	T _{STG}	- 55---- + 150							°C

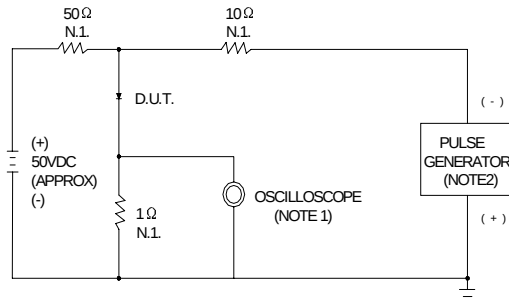
NOTE:1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $t_r=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

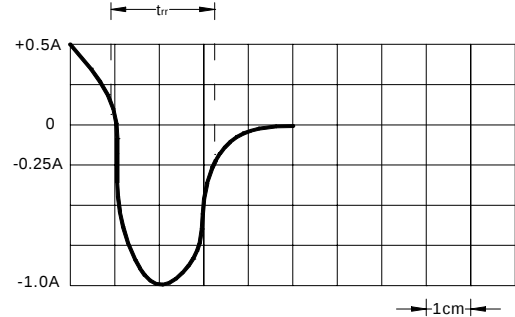
3. Thermal resistance from junction to ambient.

Ratings AND Characteristic Curves

FIG.1 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ, 22pF
2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω



SET TIME BASE FOR 50/100 ns /cm

FIG.2 – FORWARD DERATING CURVE

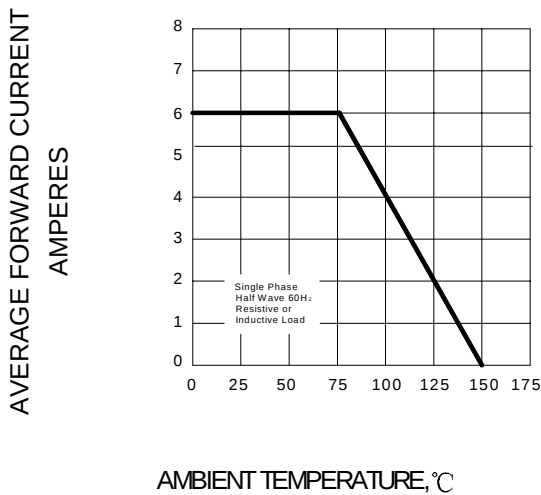


FIG.3 – PEAK FORWARD SURGE CURRENT

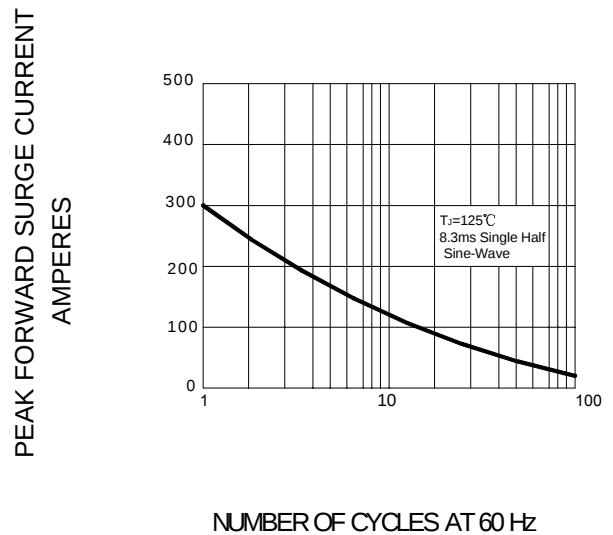


FIG.4 – TYPICAL FORWARD CHARACTERISTIC

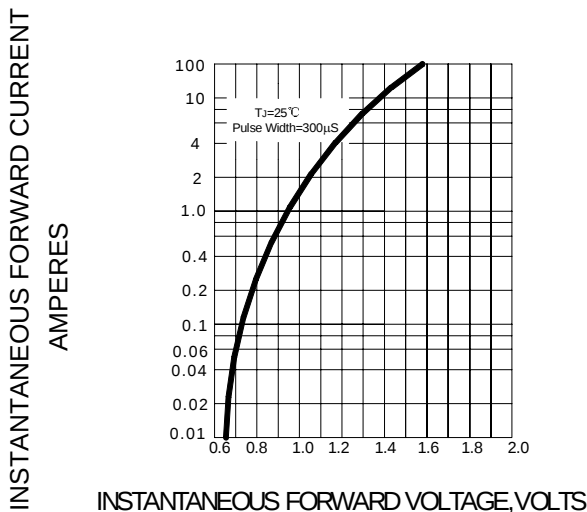


FIG.5 – PEAK JUNCTION CAPACITANCE

